

## 5.0-6.4 GHZ POWER AMPLIFIER

### Features:

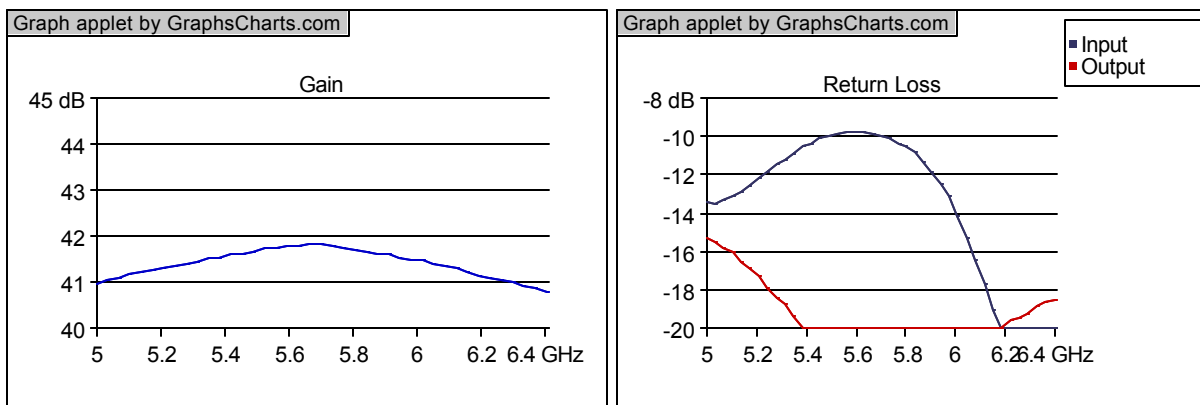
- Field Replaceable RF Connectors
- Thin Film MIC Process
- Reverse Bias Protection

### Electrical Performance

Parameter	Min.	Typ.	Max.	Unit	Note
Frequency	5.0		6.4	GHz	
Gain	40		43	dB	1
Gain Flatness			0.75	dB(+/-)	1
Power @ 1dB Gain Compression Point	27			dBm	
Output 3rd Order Intercept Point	37			dBm	
Noise Figure		3	7	dB	
VSWR Input			2.0		1
VSWR Output			2.0		1
DC Supply Voltage	12		18	V	
Supplied Current			500	mA	1

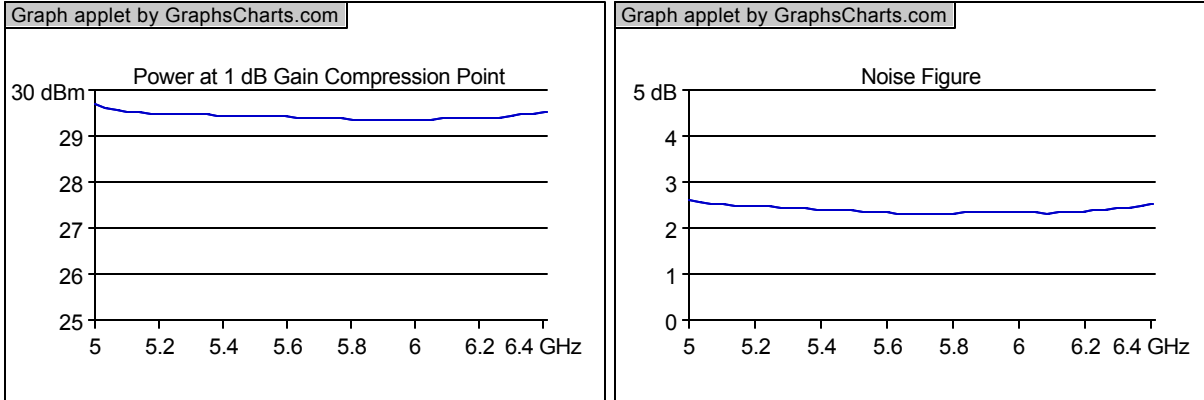
1. VDC = +12 V, Pin = -35 dBm

### Typical Test Data

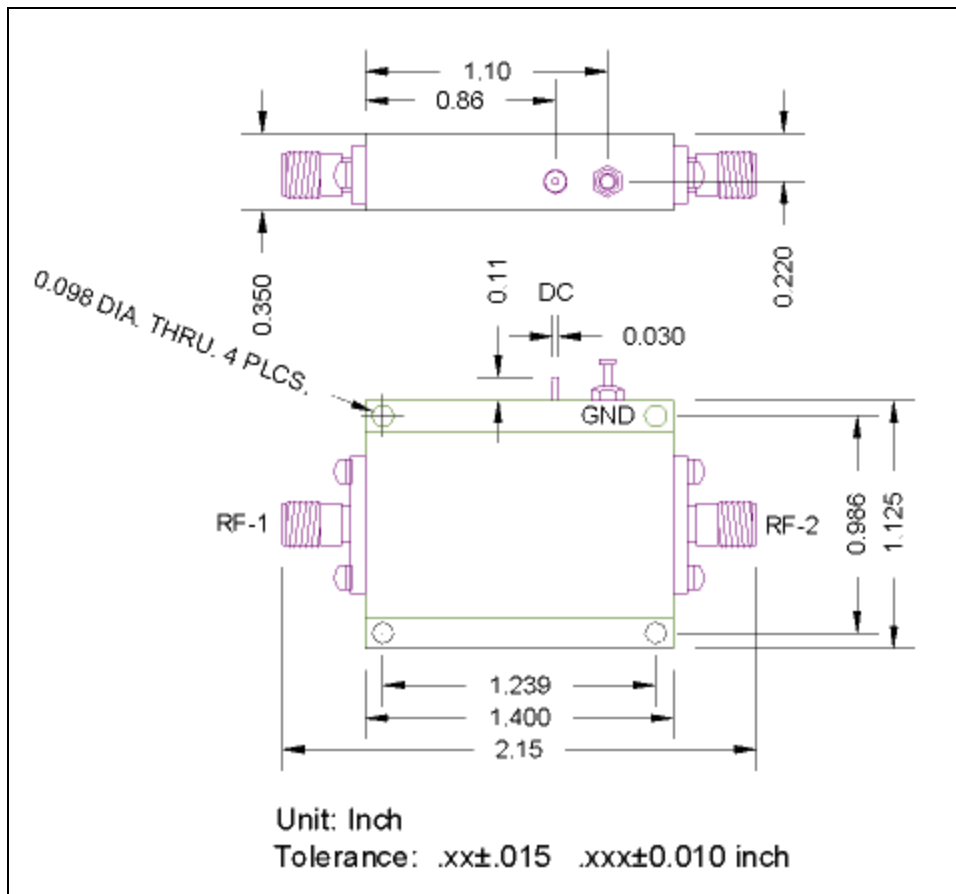


Updated: 12/30/2008

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Outline Drawing



Connector	Type	Pin #	Pin Name	In/Out	Description
RF-1	SMA-F	1	IN	I	RF SIGNAL IN

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RF-2	SMA-F	1 OUT	0	RF SIGNAL OUT
DC	EMI Filter	1 +12 V	I	DC POWER (12 TO 18 V)
GND	GROUND LUG	1 GND	0	GROUND

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